

### INVESTIGATION ON THE PERFORMANCE AND STABILITY OF Cs<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> BASED PEROVSKITE SOLAR CELLS EMPLOYING P<sub>3</sub>HT AND CuSCN HOLE TRANSPORT MATERIALS

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# Introduction



# Why solar cells?

- ◆Global warming as a result of combustion of fossil fuels
- Depletion of fossil fuels
- ◆Increase in global energy demand

# Perovskite solar cells

- Low cost materials
- ♦ High efficiencies
- Simple fabrication process

#### **Best Research-Cell Efficiencies**













#### Lead toxicity and instability in humid condition

Antimony Sb – suitable to address lead toxicity

- more stable towards moisture

• Cesium Cs - Effective for improved stability compared to methyl ammonium (MA)



#### **High performing PSC**

•Hole-transport material- thermally stable, possess high hole mobility

- Spiro-OMeTAD possesses low hole mobility (≈10<sup>-4</sup> cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>)
  - Poor conductivity
  - Copper thiocyanate (CuSCN) higher hole mobility of about 0.1 cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>, suitable energy levels, affordable and simplified synthesis routes
    - Poly (3-hexylthiophene) (P3HT) exhibit excellent thermal stability and high hole mobility



# **Objectives**



### **Main Objective**

Evaluate the effect of introducing P3HT and CuSCN hole transporting materials on the photovoltaic performance of Cs<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> perovskite solar cell.

## **Specific Objectives**

•Design and fabricate the absorber layer using Cs<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> as the absorber material

Perform optical, electrical, morphological and structural characterization of Cs<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> perovskite layer for the perovskite solar cell applications
To investigate the role of P3HT and CuSCN hole transport layers on the photovoltaic performance and stability of Cs<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> perovskite solar cells.
Assess the charge transport and recombination mechanism of the fabricated perovskite solar cells using impedance spectroscopy and surface photovoltage.



# Methodology



#### **Deposition of Electron Transport Layer**

- $\bullet$ TiO<sub>2</sub> compact layer deposited by spin coating
- ♦Annealing

### Deposition of active layer (perovskite layer)

 $Cs_3Sb_2I_9$  – Prepared by co-evaporation of CsI and SbI<sub>3</sub> in an evaporator

### Deposition of hole transport layer (HTL)

- ♦P3HT and CuSCN –Spin coated on to perovskite layer
  - Thin film of gold (back electrode) will be deposited by thermal evaporation





# Film/solar cell Characterization



- Optical characterization –UV-Vis spectroscopy
- Structural properties –XRD analysis
- Band gap shifts of perovskite thin films photoluminescence (PL).
- Deep & shallow defects in the films Photothermal deflection spectroscopy (PDS)
- Surface electronic structure of the perovskite layer x-ray photoelectron spectroscopy (XPS)
- Current density–voltage (*J*-V) characterization Solar simulator
- charge and mass (ion) transport processes in the cells electrochemical impedance analysis and surface photovoltage spectroscopy (SPS)





# THANK YOU!!!